Ultra High Dynamic Range

Monolithic Amplifier

PHA-13HLN+

 50Ω 1MHz to 1 GHz

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SOT-89 PACKAGE

The Big Deal

- Ultra-High IP3, +43 dBm typ.
- Medium Power, +28.7dBm typ.
- Excellent Noise Figure, 1.1 dB typ.

Product Overview

PHA-13HLN+ (RoHS compliant) is an advanced wideband amplifier fabricated using E-PHEMT technology and offers extremely high dynamic range over a broad frequency range and with low noise figure. In addition, the PHA-13HLN+ has good input and output return loss over a broad frequency range. PHA-13HLN+ is enclosed in a SOT-89 package and has very good thermal performance.

Key Features

| Feature | Advantages | |
|--|--|--|
| Broad Band: 1MHz to 1GHz | Broadband covering primary wireless communications bands: VHF, UHF, Cellular | |
| Extremely High IP3 38.4 dBm typical at 1MHz 43 dBm typical at 0.5GHz | i i | |
| Low Noise Figure 1.1 dB at 0.5 GHz | Enables lower system noise figure performance | |
| High P1dB 28.7 dBm at 500 MHz | High P1dB, High OIP3, Low NF results in a very dynamic range preventing amplifier saturation under strong interfering signals. It can also be used to drive mixers requiring high drive | |

Product Features

- •High IP3, 43 dBm typ. at 0.5GHz
- •Gain, 22.7 dB typ. at 0.5 GHz
- •High Pout, P1dB 28.7 dBm typ. at 0.5GHz
- •Low noise figure, 1.1 dB at 0.5 GHz



+RoHS Compliant
The +Suffix identifies RoHS Compliance. See our web site

for RoHS Compliance methodologies and qualifications

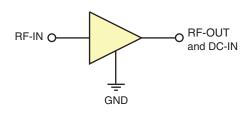
Typical Applications

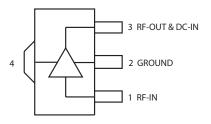
- •Base station infrastructure
- CATV
- •Cellular

General Description

PHA-13HLN+ (RoHS compliant) is an advanced wideband amplifier fabricated using E-PHEMT technology and offers extremely high dynamic range over a broad frequency range and with low noise figure. In addition, the PHA-13HLN+ has good input and output return loss over a broad frequency range. PHA-13HLN+ is enclosed in a SOT-89 package and has very good thermal performance.

simplified schematic and pin description





| Function | Pin Number | Description |
|------------------|------------|------------------------|
| RF IN | 1 | RF Input |
| RF-OUT and DC-IN | 3 | RF Output and DC Bias |
| GND | 2,4 | Connections to ground. |

Electrical Specifications¹ at 25°C, 50Ω, unless noted

| Parameter | Condition | | Vd=8V ¹ | | |
|--|-----------|------|--------------------|------|-------|
| | (MHz) | Min. | Тур. | Max. | |
| requency Range | | 1 | | 1000 | MHz |
| | 1 | 22.4 | 25.0 | 27.4 | |
| | 20 | _ | 24.3 | _ | |
| Gain | 250 | _ | 23.0 | _ | dB |
| | 500 | 20.4 | 22.7 | 25.0 | |
| | 1000 | _ | 20.4 | _ | |
| | 1 | | 10.8 | | |
| | 20 | | 15.8 | | |
| nput Return Loss | 250 | | 16.7 | | dB |
| | 500 | | 17.5 | | |
| | 1000 | | 10.5 | | |
| | 1 | | 11.2 | | |
| | 20 | | 18.8 | | |
| Output Return Loss | 250 | | 17.7 | | dB |
| | 500 | | 29.4 | | |
| | 1000 | | 9.0 | | |
| Reverse isolation | 500 | | 26.3 | | dB |
| | 1 | | 26.2 | | |
| | 20 | | 27.3 | | |
| Output Power @1 dB compression | 250 | | 28.4 | | dBm |
| | 500 | | 28.7 | | |
| | 1000 | | 27.4 | | |
| | 1 | _ | 38.4 | _ | |
| | 20 | _ | 41.7 | - | |
| Output IP3 ² | 250 | _ | 43.5 | _ | dBm |
| | 500 | 40.0 | 43.0 | - | |
| | 1000 | _ | 42.2 | _ | |
| | 1 | | 3.0 | | |
| | 20 | | 1.2 | | |
| Noise Figure | 250 | | 1.1 | | dB |
| | 500 | | 1.1 | | |
| | 1000 | | 1.4 | | |
| Device Operating Voltage | | | 8.0 | | V |
| Device Operating Current | | _ | 234.1 | 251 | mA |
| Device Current Variation vs. Temperature ³ | | | -100.6 | | μΑ/°C |
| Device Current Variation vs Voltage | | | 0.0155 | | mA/mV |
| Thermal Resistance, junction-to-ground lead lunction-to-ground lead at 85°C stage temperature | | | 23.3 | | °C/W |

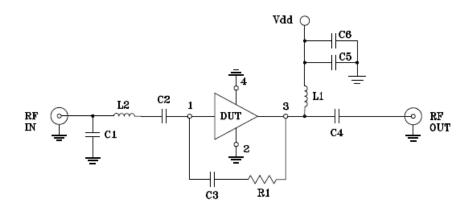
Measured on Mini-Circuits Characterization test board TB-969-13HLN+. See Characterization Test Circuit (Fig. 1)
 Tested at Pout= 0 dBm / tone.
 (Current at 85°C — Current at -45°C)/130

Absolute Maximum Ratings⁴

| Parameter | Ratings | | | |
|-------------------------------------|---|--|--|--|
| Operating Temperature (ground lead) | -40°C to 95°C | | | |
| Storage Temperature | -65°C to 150°C | | | |
| Power Dissipation | 3.3 W ⁵ | | | |
| Input Power (CW) | +21 dBm (5 minutes max) ⁶ +10 dBm (continuous) for 1-10 MHz +11 dBm (continuous) for 10-1000 MHz | | | |
| DC Voltage on Pin 3 | 10V | | | |

^{4.} Permanent damage may occur if any of these limits are exceeded.
Electrical maximum ratings are not intended for continuous normal operation.
5. up to 85°C, derate linearly to 2.5 W at 95°C.
6. up to 85°C, derate linearly to 18 dBm at 95°C.

Characterization Test / Recommended Application Circuit



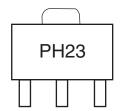
| Components | Size | Value | Manufacturer | P/N |
|------------|------|---------|--------------|-------------------|
| C1 | 0402 | 1.5 pF | | GRM1555C1H1R5CZ01 |
| C2 | 0603 | 2.2 uF | Ī | GRM188R61C225KE15 |
| C3 | 0402 | 0.1uF | | GRM155R71C104KA88 |
| C4 | 0603 | 2.2 uF | Murata | GRM188R61C225KE15 |
| C5 | 0402 | 1000 pF | [| GRM1555C1H102JA01 |
| C6 | 0805 | 10 uF | Ī | GRM21BR61C106KE15 |
| L1 | 1210 | 15 uH | | LQH32DN150K53L |
| L2 | 0603 | 5.1 nH | Coilcraft | 0603CS-5N1XJL |
| R1 | 0402 | 1500 Ω | KoA | RK73H1ET1501F |

Fig 1. Block Diagram of Test Circuit used for characterization. (DUT soldered on Mini-Circuits Characterization test board TB-969-13HLN+) Gain, Return loss, Output power at 1dB compression (P1dB), output IP3 (OIP3) and noise figure measured using Agilent's N5242A PNA-X microwave network analyzer.

Conditions:

- 1. Gain and Return loss: Pin= -25dBm
- 2. Output IP3 (OIP3): Two tones, spaced 0.5 MHz apart, 0 dBm/ tone at output.

Product Marking



Marking may contain other features or characters for internal lot control

| Additional Detailed Technical Information additional information is available on our dash board. To access this information click here | | |
|--|--|--|
| | Data Table | |
| Performance Data | Swept Graphs | |
| | S-Parameter (S2P Files) Data Set (.zip file) | |
| Case Style | DF782 (SOT 89) Plastic package, exposed paddle lead finish: Matt-Tin | |
| Tape & Reel | F55 | |
| Standard quantities available on reel | 7" reels with 20, 50, 100, 200, 500 or 1K devices | |
| Suggested Layout for PCB Design | PL-523 | |
| Evaluation Board | TB-969-13HLN+ | |
| Environmental Ratings | ENV08T9 | |

ESD Rating

Human Body Model (HBM): Class 1B (Pass 500 V) in accordance with ANSI/ESD STM 5.1 - 2001

MSL Rating

Moisture Sensitivity: MSL1 in accordance with IPC/JEDEC J-STD-020D

Start Visual Inspection Reflow 3 cycles, 260°C Visual Inspection Soak 85°C/85RH 168 hours Visual Inspection Electrical Test SAM Analysis Stop

Additional Notes

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
- B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.
- C. The parts covered by this specification document are subject to Mini-Circuits standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the Standard Terms and the exclusive rights and remedies thereunder, please visit Mini-Circuits' website at www.minicircuits.com/MCLStore/terms.jsp

